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(Not for submission under 37 CFR 1.99)

Application Number	10596726
Filing Date	2004-12-24
First Named Inventor	YANSON et al.
Art Unit	2828
Examiner Name	Not Yet Assigned
Attorney Docket Number	35832.000130

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/A.P./	1	YI, H. et al., "Effect of dielectric and semiconductor cap layer combinations in impurity free vacancy disordering of an InGaAs/InGaAsP single quantum well structure", Sae Mulli. Vol. 41, pp.193-8 (Sept. 2000) (Korean language version only available)	<input type="checkbox"/>
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/A.P./	3	SU, Y. et al., "Effects of In/sub0.53/Ga/sub0.47 cap layer and stoichiometry of dielectric capping layers on impurity-free vacancy disordering of In/sub 0.53 Ga/sub 0.47/As/InP multiquantum well structures", J. Appl. Phys. 88:5720-3 (2000)	<input type="checkbox"/>
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/A.P./	7	SUDOH, T. et al., "Wavelength trimming of distributed-feedback lasers by photo-absorption-induced disordering", Conference Proceedings LEOS '96 9th Annual Meeting IEEE Lasers and Electro Optics Soc, pp. 419-20 (1996)	<input type="checkbox"/>
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